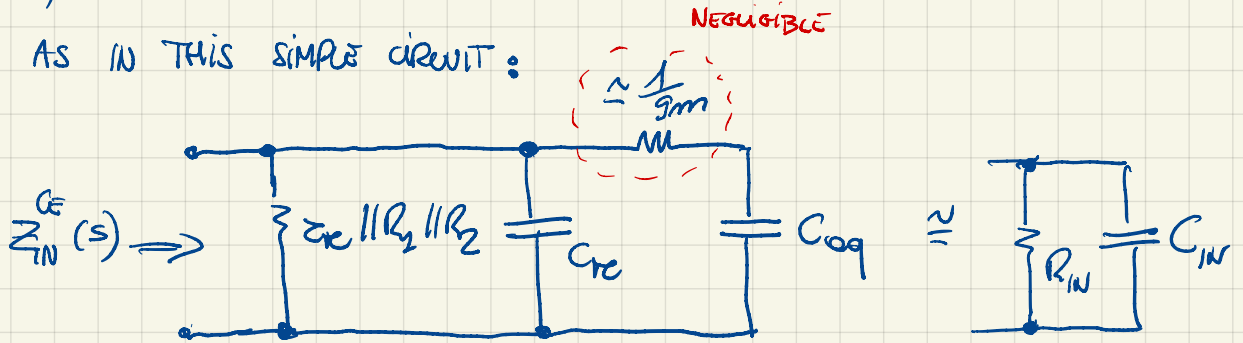


$$Z_{re}(s) = \frac{1}{sC_{\mu}(1+g_m R_c')} + \frac{s\mu R_c'}{sC_{\mu}(1+g_m R_c')} = \frac{1}{sC_{eq}} + \underbrace{R_c' \parallel \frac{1}{g_m}}_{\approx \frac{1}{g_m}}$$

AS A RESULT, WE FOUND THAT

$Z_{in}(s)$  IS AS IN THIS SIMPLE CIRCUIT:

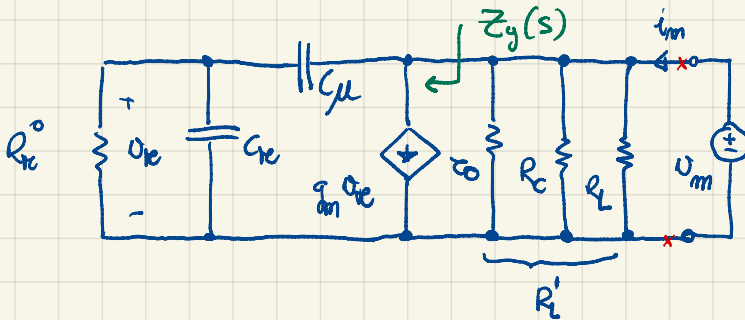


$$R_{in} = r_{re} \parallel R_1 \parallel R_2 \quad C_{in} \approx C_{re} + C_{\mu} (1 + g_m R_c') \leftarrow \begin{matrix} \text{MILLER} \\ \text{EFFECT} \end{matrix}$$

CE INPUT RESISTANCE MILLER MULTIPLIER

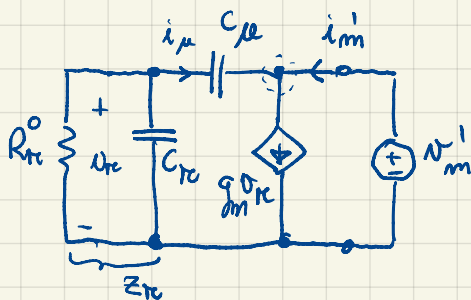
CONCLUSION: THE CE INPUT IMPEDANCE HAS A STRONG CAPACITIVE COMPONENT THAT IS DOMINATED BY  $C_{\mu}$ , THROUGH **MILLER EFFECT**

◇ LET'S NOW DETERMINE  $Z_o(s)$



$$Z_o(s) \triangleq \frac{V_m(s)}{I_m(s)}$$

$$Z_o(s) = R_c' \parallel Z_y(s)$$



$$Z_y(s) \triangleq \frac{V_m'(s)}{I_m'(s)}$$

$$\begin{cases} i_m' = g_m v_{re} - i_{\mu} = g_m v_{re} - sC_{\mu}(v_{re} - v_m') = (g_m - sC_{\mu})v_{re} + sC_{\mu}v_m' \\ v_{re} = v_m' \cdot \frac{Z_{re}}{Z_{re} + \frac{1}{sC_{\mu}}} \end{cases}$$

$$N_{re} = \sigma_{m1} \frac{\frac{R_{re}^0}{1 + s C_{re} R_{re}^0}}{\frac{R_{re}^0}{1 + s C_{re} R_{re}^0} + \frac{1}{s C_{\mu}}} = \sigma_{m1} \cdot \frac{s C_{\mu} (1 + s C_{re} R_{re}^0) R_{re}^0}{(1 + s C_{re} R_{re}^0) [1 + s R_{re}^0 (C_{\mu} + C_{re})]}$$

REPLACING INTO THE 1<sup>ST</sup> EQUATION

$$i_{m1} = \sigma_{m1} s C_{\mu} - (s C_{\mu} - g_m) \frac{s C_{\mu} R_{re}^0 (1 + s C_{re} R_{re}^0)}{(1 + s C_{re} R_{re}^0) [1 + s R_{re}^0 (C_{re} + C_{\mu})]} \sigma_{m1}$$

$$Z_y(s) = \frac{\sigma_{m1}}{i_{m1}} = \frac{1 + s R_{re}^0 (C_{\mu} + C_{re})}{s C_{\mu} (1 + g_m R_{re}^0 + s C_{re} R_{re}^0)} = \frac{1}{s C_{\mu} (1 + g_m R_{re}^0)} \cdot \frac{1 + s R_{re}^0 (C_{re} + C_{\mu})}{1 + s C_{re} \frac{R_{re}^0}{1 + g_m R_{re}^0}}$$

$$i_{m1} = \sigma_{m1} \cdot \frac{s C_{\mu} (1 + s C_{re} R_{re}^0) [1 + s R_{re}^0 (C_{re} + C_{\mu})] + (g_m - s C_{\mu}) s C_{\mu} R_{re}^0 (1 + s C_{re} R_{re}^0)}{(1 + s C_{re} R_{re}^0) [1 + s R_{re}^0 (C_{re} + C_{\mu})]} =$$

$$= \sigma_{m1} \cdot \frac{s C_{\mu} + s^2 C_{\mu} R_{re}^0 (C_{re} + C_{\mu}) + s C_{\mu} R_{re}^0 g_m - s^2 C_{\mu} R_{re}^0}{1 + s R_{re}^0 (C_{re} + C_{\mu})} =$$

$$= \sigma_{m1} \cdot \frac{s C_{\mu} (1 + s C_{re} R_{re}^0 + g_m R_{re}^0)}{1 + s R_{re}^0 (C_{re} + C_{\mu})}$$

IN CONCLUSION

$$Z_0(s) = R_L \parallel Z_y(s)$$

WHERE

$$Z_y(s) = \frac{1}{s C_{out}} \cdot \frac{1 + s/\omega_z^y}{1 + s/\omega_p^y}$$

CAPACITIVE COMPONENT (SMALLER THAN THE INPUT'S)

SAME SIZE OF  $C_{re}$  APPROXIMATELY!

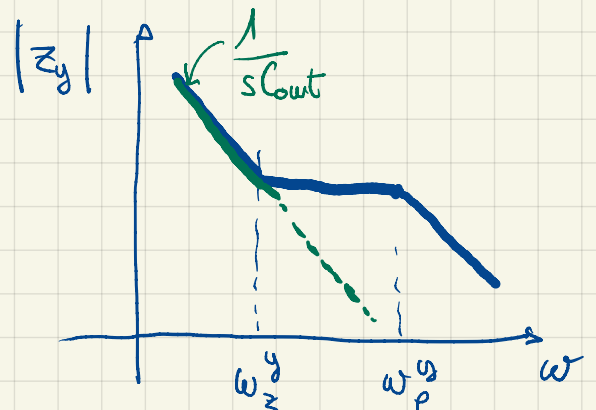
$$C_{out} = C_{\mu} (1 + g_m R_{re}^0)$$

$$\omega_z^y = \frac{1}{R_{re}^0 (C_{re} + C_{\mu})} \ll \omega_p^y$$

$$\omega_p^y = \frac{1}{C_{re}} \cdot \frac{1 + g_m R_{re}^0}{R_{re}^0} \approx \frac{1}{C_{re}} \cdot g_m \approx \omega_T$$

$\uparrow$   
 $g_m R_{re}^0 \gg 1$

ZERO-POLE COUPLE



CONCLUSION:  $Z_0(s)$  HAS AGAIN CAPACITIVE STRUCTURE, WITH LOWER EQUIVALENT CAPACITANCE COMPARED TO  $Z_w(s)$

# ◇ GAIN · BANDWIDTH PRODUCT FOR CE AMPLIFIERS

$$GBP = |A_{v0}^{MB}| \cdot \omega_H$$

$$|A_{v0}^{MB}| = \frac{R_{th}^0}{R_s} \cdot g_m R_L'$$

$$\omega_H \approx \frac{1}{\alpha_1} = \frac{1}{C_{\mu} R_{th}^0 + C_{\mu} R_{in}^0} \approx \frac{1}{R_{in}^0 (C_{\mu} + C_{\mu} g_m R_L')}$$

$$GBP \approx \frac{R_L'}{R_s} \cdot \frac{1}{\frac{C_{\mu}}{g_m} + R_L' C_{\mu}}$$

$$R_{in}^0 = (R_L') + R_{in}^0 (1 + g_m R_L') \approx R_{in}^0 (1 + g_m R_L')$$

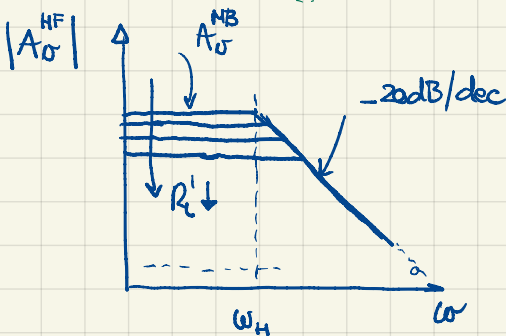
$$\approx g_m R_{in}^0 R_L'$$

» **LIGHT LOAD OPERATION:**  $R_L$  IS RELATIVELY LARGE

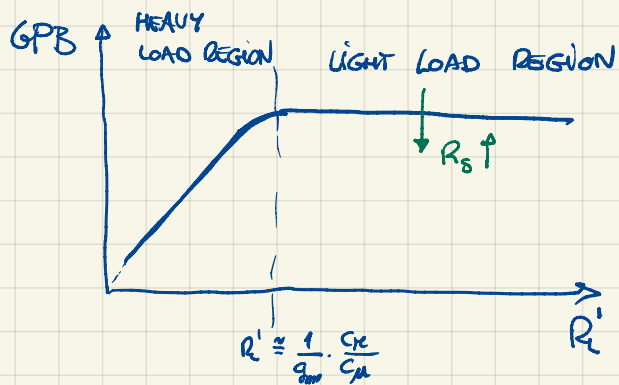
WE ARE ASSUMING THAT TRANSISTOR PARAMETERS ( $g_m, C_{\mu}, C_{re}, r_o, \dots$ ) DO NOT DEPEND ON  $R_L$  (I.E. THE PHYSICAL LOAD RESISTANCE)

IN LIGHT LOAD CONDITIONS  $R_L' C_{\mu} \gg \frac{C_{\mu}}{g_m} \Leftrightarrow g_m R_L' \gg \frac{C_{\mu}}{C_{\mu}}$  ( $\omega \ll \omega_T$ )  
SO THAT

$$GBP \approx \frac{1}{R_s C_{\mu}} \quad \text{CONSTANT WITH } R_L$$



$R_L' \downarrow \Rightarrow A_{v0}^{MB} \downarrow \quad \omega_H \uparrow$   
 $\underbrace{A_{v0}^{MB} \cdot \omega_H}_{GBP} \text{ IS CONSTANT}$



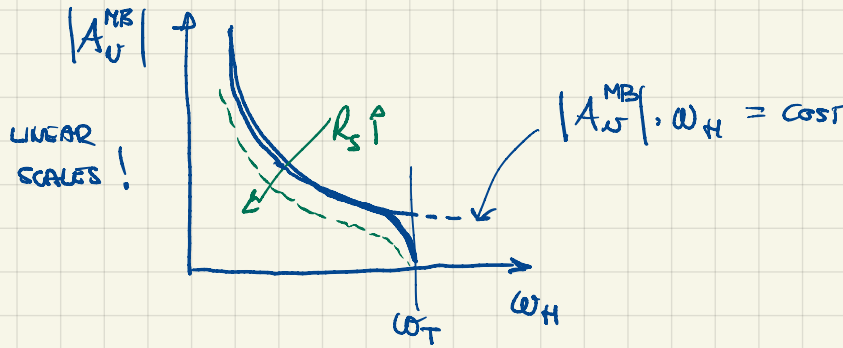
» IN THE **HEAVY LOAD REGION:**

$$\frac{C_{\mu}}{g_m} \gg R_L' C_{\mu}$$

AND THEREFORE

$$GBP \approx \frac{g_m R_L'}{R_s C_{\mu}} \propto R_L'$$

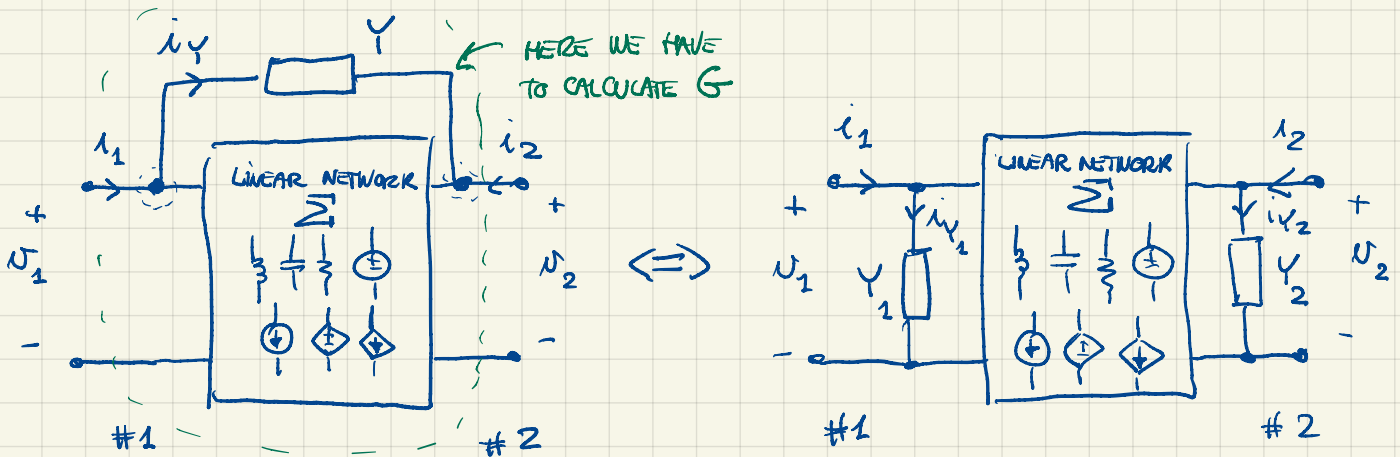
PUSHING  $R_L'$  DOWN, GBP DECREASES LINEARLY AS THE AMPLIFICATION DOES  $\Rightarrow$   
 $\omega_H \approx \omega_T$



AT HEAVY LOADS  $\omega_H$  STOPS GROWING AND TENDS TO  $\omega_T$  AS THE MID-BAND GAIN GOES DOWN.

IMPORTANT CONCLUSION: IT IS NOT POSSIBLE TO HAVE HIGH GAIN AND LARGE BANDWIDTH AT THE SAME TIME FROM A SINGLE STAGE CE AMPLIFIER !!

## MILLER'S THEOREM



MILLER'S THEOREM STATES THE TWO CIRCUITS ARE EQUIVALENT (I.E. THEY HAVE THE SAME CURRENTS AND VOLTAGES) IF AND ONLY IF

$$\begin{cases} i_{Y_1} = i_Y \\ i_{Y_2} = -i_Y \end{cases} \Leftrightarrow \begin{cases} U_1 Y_1 = Y(U_1 - U_2) \\ U_2 Y_2 = -Y(U_1 - U_2) \end{cases} \Leftrightarrow$$

$$\Leftrightarrow \begin{cases} Y_1 = Y \left(1 - \frac{U_2}{U_1}\right) = Y(1 - G) \\ Y_2 = -Y \left(\frac{U_1}{U_2} - 1\right) = Y \left(1 - \frac{1}{G}\right) \end{cases}$$

$$G \stackrel{\text{def}}{=} \frac{U_2}{U_1}$$

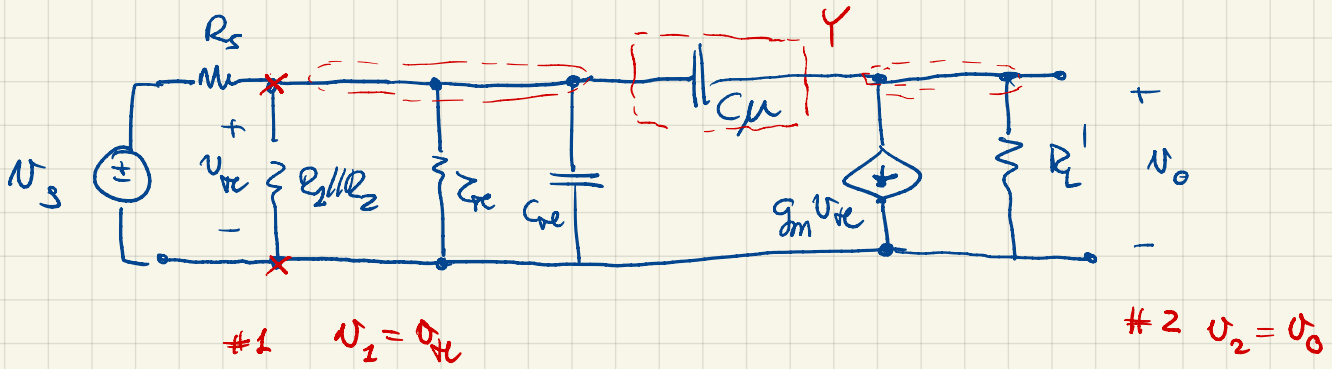
MUST BE KNOWN !!

NOW IF  $|G| \gg 1$

$$Y_1 \approx -GY$$

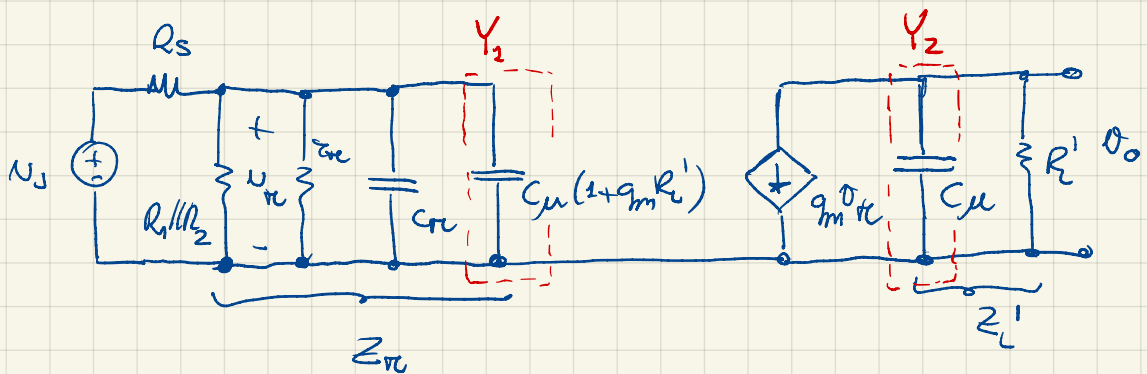
$$Y_2 \approx Y$$

LET'S REVISE THE CE AMPLIFIER USING MILLER'S THEOREM



$$G \approx \left. \frac{v_o}{v_{rc}} \right|_{MS} = -g_m R_L' \quad |G| \gg 1$$

APPLYING THE THEOREM WE CAN SIMPLIFY THE CIRCUIT AS



$$A_v^{HF}(s) = -\frac{Z_{rc}}{R_s + Z_{rc}} \cdot g_m \cdot Z_L'$$